# NPN Silicon General Purpose Amplifier Transistor

This NPN transistor is designed for general purpose amplifier applications. This device is housed in the SC-75/SOT-416 package which is designed for low power surface mount applications, where board space is at a premium.

### **Features**

- Reduces Board Space
- High h<sub>FE</sub>, 210-460 (typical)
- Low  $V_{CE(sat)}$ , < 0.5 V
- Available in 8 mm, 7 inch/3000 Unit Tape and Reel
- AEC-Q101 Qualified and PPAP Capable
- S Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant\*



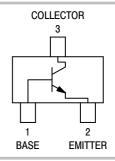
# ON Semiconductor®

http://onsemi.com

# NPN GENERAL PURPOSE AMPLIFIER TRANSISTORS SURFACE MOUNT



SC-75 CASE 463-01 STYLE 1



#### **MARKING DIAGRAM**



B9 = Device Code
M = Date Code\*
• = Pb-Free Package

(Note: Microdot may be in either location)

\*Date Code orientation may vary depending upon manufacturing location.

#### ORDERING INFORMATION

Device	Package	Shipping <sup>†</sup>
2SC4617G	SC-75 (Pb-Free)	3,000/Tape & Reel
S2SC4617G	SC-75 (Pb-Free)	3,000/Tape & Reel
2SC4617T1G	SC-75 (Pb-Free)	3,000/Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

<sup>\*</sup>For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

## **MAXIMUM RATINGS** $(T_J = 25^{\circ}C)$

Rating	Symbol	Value	Unit	
Collector-Base Voltage	V <sub>(BR)CBO</sub>	50	Vdc	
Collector-Emitter Voltage	V <sub>(BR)CEO</sub>	50	Vdc	
Emitter-Base Voltage	V <sub>(BR)EBO</sub>	5.0	Vdc	
Collector Current – Continuous	Ic	100	mAdc	

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Power Dissipation (Note 1)	P <sub>D</sub>	125	mW
Junction Temperature	TJ	150	°C
Storage Temperature Range	T <sub>stg</sub>	−55 ~ +150	°C

<sup>1.</sup> Device mounted on a FR-4 glass epoxy printed circuit board using the minimum recommended footprint.

# **ELECTRICAL CHARACTERISTICS** $(T_A = 25^{\circ}C)$

Characteristic	Symbol	Min	Тур	Max	Unit
Collector-Base Breakdown Voltage (I <sub>C</sub> = 50 μAdc, I <sub>E</sub> = 0)	V <sub>(BR)CBO</sub>	50	-	-	Vdc
Collector-Emitter Breakdown Voltage (I <sub>C</sub> = 1.0 mAdc, I <sub>B</sub> = 0)	V <sub>(BR)CEO</sub>	50	-	-	Vdc
Emitter-Base Breakdown Voltage ( $I_E = 50 \mu Adc, I_E = 0$ )	V <sub>(BR)EBO</sub>	5.0	-	-	Vdc
Collector-Base Cutoff Current (V <sub>CB</sub> = 30 Vdc, I <sub>E</sub> = 0)	I <sub>CBO</sub>	-	-	0.5	μΑ
Emitter-Base Cutoff Current (V <sub>EB</sub> = 4.0 Vdc, I <sub>B</sub> = 0)	I <sub>EBO</sub>	-	-	0.5	μΑ
Collector-Emitter Saturation Voltage (Note 2) (I <sub>C</sub> = 60 mAdc, I <sub>B</sub> = 5.0 mAdc)	V <sub>CE(sat)</sub>	_	-	0.4	Vdc
DC Current Gain (Note 2) $(V_{CE} = 6.0 \text{ Vdc}, I_{C} = 1.0 \text{ mAdc})$	h <sub>FE</sub>	120	-	560	_
Transition Frequency ( $V_{CE}$ = 12 Vdc, $I_{C}$ = 2.0 mAdc, f = 30 MHz)	f <sub>T</sub>	-	180	-	MHz
Output Capacitance (V <sub>CB</sub> = 12 Vdc, I <sub>C</sub> = 0 Adc, f = 1 MHz)	C <sub>OB</sub>	-	2.0	-	pF

<sup>2.</sup> Pulse Test: Pulse Width ≤ 300 µs, D.C. ≤ 2%.

### TYPICAL ELECTRICAL CHARACTERISTICS

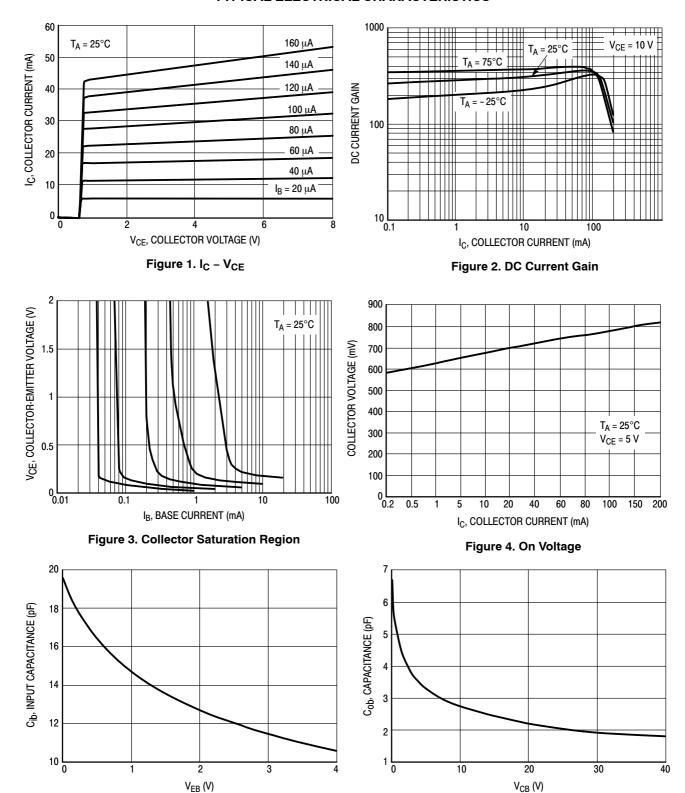
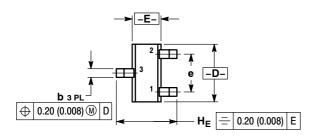


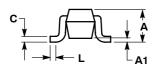
Figure 5. Capacitance

Figure 6. Capacitance

### PACKAGE DIMENSIONS

SC-75/SOT-416 CASE 463-01 ISSUF F





#### NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI
   V14 FM 1092
- 2. CONTROLLING DIMENSION: MILLIMETER.

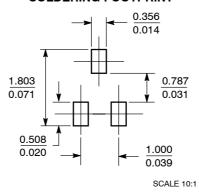
	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.70	0.80	0.90	0.027	0.031	0.035
A1	0.00	0.05	0.10	0.000	0.002	0.004
b	0.15	0.20	0.30	0.006	0.008	0.012
С	0.10	0.15	0.25	0.004	0.006	0.010
D	1.55	1.60	1.65	0.059	0.063	0.067
Е	0.70	0.80	0.90	0.027	0.031	0.035
е	1.00 BSC			C	0.04 BSC	
L	0.10	0.15	0.20	0.004	0.006	0.008
HE	1.50	1.60	1.70	0.061	0.063	0.065

STYLE 1: PIN 1. E

> (mm inches

PIN 1. BASE 2. EMITTER 3. COLLECTOR

#### **SOLDERING FOOTPRINT\***



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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